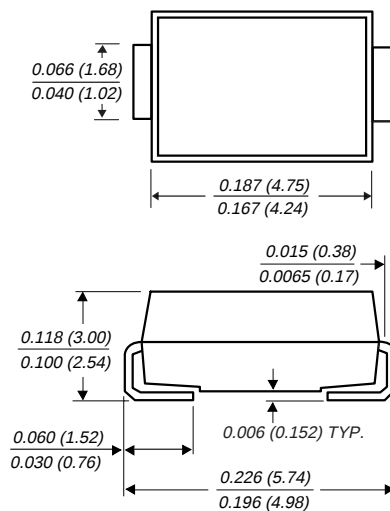


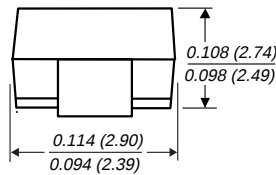
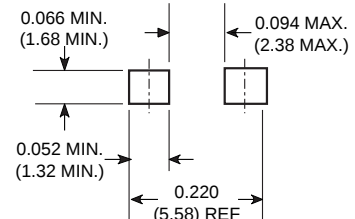
**Surface Mount Glass Passivated Junction
Fast Switching Rectifier****Reverse Voltage** 50 to 1000V
Forward Current 1.0A

DO-214BA (GF1)



Dimensions in inches and (millimeters)

Glass-plastic encapsulation technique is covered by Patent No. 3,996,602, brazed-lead assembly by Patent No. 3,930,306 and lead forming by Patent No. 5,151,846

**Mounting Pad Layout****Features**

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- Ideal for surface mount automotive applications
- High temperature metallurgically bonded construction
- Cavity-free glass passivated junction
- Capable of meeting environmental standards of MIL-S-19500
- Built-in strain relief • Easy pick and place
- Fast switching for high efficiency
- High temperature soldering guaranteed: 450°C/5 seconds at terminals.
- Complete device submersible temperature of 265°C for 10 seconds in solder bath

Mechanical Data**Case:** JEDEC DO-214BA, molded plastic over glass body**Terminals:** Solder plated, solderable per MIL-STD-750, Method 2026**Polarity:** Color band denotes cathode end**Mounting Position:** Any **Weight:** 0.0048 oz, 0.12 g**Packaging codes/options:**

19/6.5K per 13" Reel (12mm Tape)

17/1.5K per 7" Reel (12mm Tape)

Maximum Ratings & Thermal Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	RGF1A	RGF1B	RGF1D	RGF1G	RGF1J	RGF1K	RGF1M	Unit
Device marking code		RA	RB	RD	RG	RJ	RK	RM	
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at T _L = 120°C	I _{F(AV)}	1.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30							A
Max. full load reverse current, full cycle average T _A = 55°C	I _{R(AV)}	50							μA
Typical thermal resistance ⁽¹⁾	R _{θJA}	80							°C/W
	R _{θJL}	28							
Operating junction and storage temperature range	T _J ,T _{STG}	−65 to +175							°C

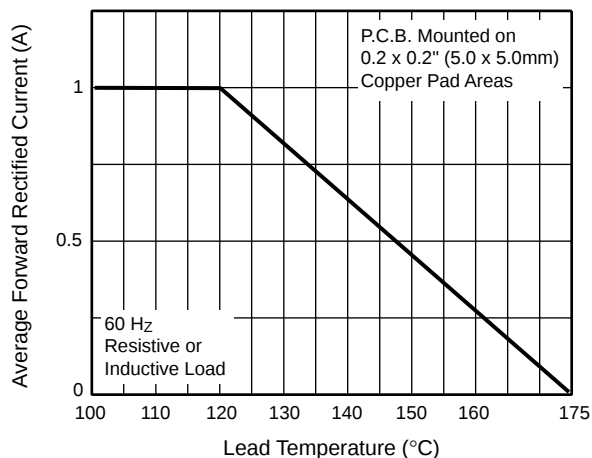
Electrical Characteristics ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	RGF1A	RGF1B	RGF1D	RGF1G	RGF1J	RGF1K	RGF1M	Unit
Maximum instantaneous forward voltage at 1.0A	V _F	1.30							V
Maximum DC reverse current at rated DC blocking voltage	I _R	5.0 100							μA
Typical reverse recovery time at I _F = 0.5A, I _R = 1.0A, I _{rr} = 0.25 A	t _{rr}	150				250	500		ns
Typical junction capacitance at 4.0V, 1MHz	C _J	8.5							pF

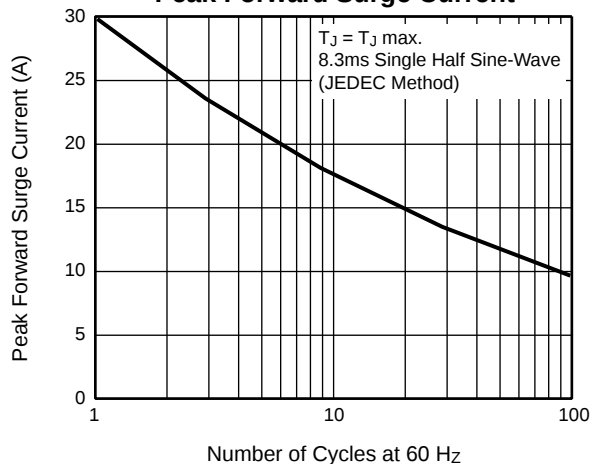
Note: (1) Thermal resistance from junction to ambient and from junction to lead, P.C.B. mounted on 0.2 x 0.2" (5.0 x 5.0mm) copper pad areas

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

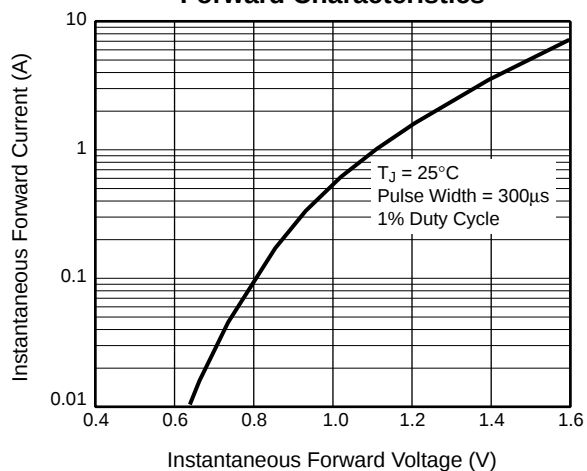
**Fig. 1 – Forward Current
Derating Curve**



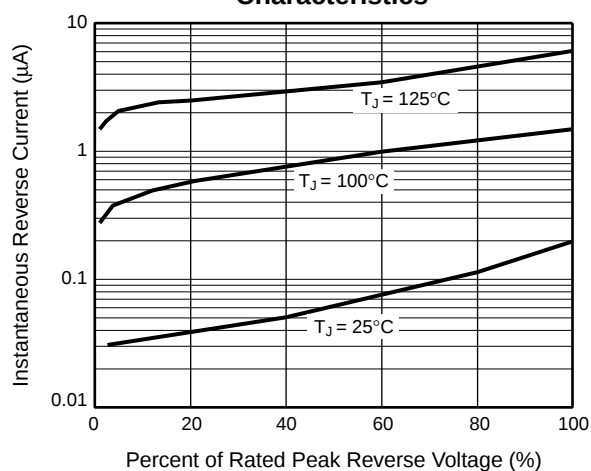
**Fig. 2 – Maximum Non-Repetitive
Peak Forward Surge Current**



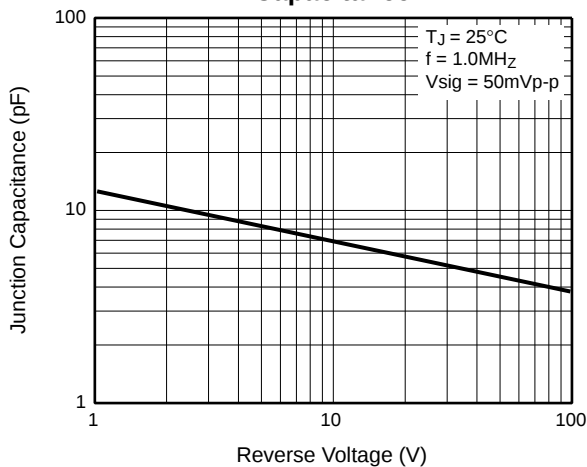
**Fig. 3 – Typical Instantaneous
Forward Characteristics**



**Fig. 4 – Typical Reverse
Characteristics**



**Fig. 5 – Typical Junction
Capacitance**



**Fig. 6 – Typical Transient
Thermal Impedance**

